Electronic Supplementary Information

Large mass field fluctuation and lattice anharmonicity effects promote thermoelectric and mechanical performances in NbFeSb half-heusler alloys via Ti/Zr/Hf stepwise doping

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Supplementary Figures



Fig. S1. Rietveld refinement result of the Nb_{1-x-y-z}Ti_xZr_yHf_zFeSb (x, y, z = 0, 0.05, 0.07) sample.



Fig. S2. (a) Scanning electron microscopy (SEM) image of a polished surface of the $Nb_{0.79}Ti_{0.07}Zr_{0.07}Hf_{0.07}FeSb$ sample. (b) Corresponding energy dispersive spectrometry (EDS) and mappings of (c) Nb, (d) Fe, (e) Sb, (f) Ti, (g) Zr, (h) Hf.



Fig. S3. X-ray photoelectron spectra (XPS) of the $Nb_{0.82}Ti_{0.06}Zr_{0.06}Hf_{0.06}FeSb$ sample for (a) full spectrum, (b) Fe 2p, (c) Sb 3d.



Fig S4. X-ray photoelectron spectra (XPS) of the $Nb_{0.82}Ti_{0.06}Zr_{0.06}Hf_{0.06}FeSb$ sample for (a) Nb 3d, (b) Ti 2p, (c) Zr 3d, (d) Hf 4f.



Fig. S5. The |S|-dependent Log₁₀(n) calculated by the simple Equation, the SPB model.



Fig. S6. Temperature-dependent (a) thermal diffusivity D and (b) heat capacity C_p



Fig. S7. (a) Calculated Lorentz number using the SPB model and (b) Electronic thermal conductivity for the Nb_{1-x-y-z}Ti_xZr_yHf_zFeSb (x, y, z = 0, 0.05, 0.06, 0.07) samples.



Fig. S8. The temperature dependence of lattice thermal conductivity of Nb_{1-x-y-z}Ti_xZr_yHf_zFeSb (x, y,

z = 0, 0.05, 0.06, 0.07) sample and fitting by Debye-Callaway model.



Fig. S9. Experimental and theoretical curves for κ_{lat} of the samples of x = y = z = 0.06.



Fig. S10. Powder XRD patterns of $Nb_{0.79}Ti_{0.07}Zr_{0.07}Hf_{0.07}FeSb$ sample 1 and 2.

Supplementary Tables

Table S1. The mixing entropy, mixing enthalpy and mixing Gibbs free energy at 1123 K for the Nb₁.

<i>x</i> , <i>y</i> , <i>z</i>	$\Delta S (J \text{ mol}^{-1} \text{ K}^{-1})$	$\Delta H (KJ mol^{-1})$	$\Delta G (KJ \text{ mol}^{-1})$
x = y = z = 0	0	0	0
x = 0.05, y = z = 0	1.65	0.38	-1.47
x = y = 0.05, z = 0	3.28	1.08	-2.60
x = y = z = 0.05	4.88	1.74	-3.74
x = y = z = 0.06	5.56	1.85	-4.40
x = y = z = 0.07	6.19	1.94	-5.01

 $_{x-y-z}$ Ti_xZr_yHf_zFeSb (x, y, z = 0, 0.05, 0.06, 0.07) samples.

Table S2. The Rietveld refinement details of $Nb_{1-x-y-z}Ti_xZr_yHf_zFeSb$ (x, y, z = 0, 0.05, 0.06, 0.07)

samples.

0.07) samples.

<i>x</i> , <i>y</i> , <i>z</i>	R _p	R _{wp}	χ^2	a (Å)
x = y = z = 0	6.19	9.00	4.06	5.9534
x = 0.05, y = z = 0	3.12	4.71	4.72	5.9462
x = y = 0.05, z = 0	3.14	4.62	4.44	5.9522
x = y = z = 0.05	3.00	4.22	4.06	5.9578
x = y = z = 0.06	2.80	3.81	2.83	5.9656
x = y = z = 0.07	2.92	3.98	2.93	5.9677

Table S3. Actual and nominal composition of the Nb_{1-x-y-z}Ti_xZr_yHf_zFeSb (x, y, z = 0, 0.05, 0.06,

Nominal	A stual composition	SEM/EDS composition (at %)					
composition	Actual composition	Nb	Ti	Zr	Hf	Fe	Sb
x = y = z = 0	$Nb_{1.02}Fe_{0.98}Sb$	34.3				32.8	33.0
x = 0.05, y = z = 0	$Nb_{0.97}Ti_{0.05}Fe_{0.98}Sb_{0.99}$	32.4	1.7			32.8	33.0
x = y = 0.05, z = 0	$Nb_{0.92}Ti_{0.05}Zr_{0.05}Fe_{0.99}Sb_{0.99}$	30.7	1.6	1.8		33.1	32.9
x = y = z = 0.05	$Nb_{0.88}Ti_{0.05}Zr_{0.05}Hf_{0.05}Fe_{0.96}Sb$	29.6	1.8	1.6	1.7	32.1	33.3
x = y = z = 0.06	$Nb_{0.86}Ti_{0.06}Zr_{0.05}Hf_{0.06}Fe_{0.98}Sb$	28.5	1.9	1.8	2.1	32.6	33.1
x = y = z = 0.07	$Nb_{0.81}Ti_{0.07}Zr_{0.07}Hf_{0.07}Fe_{0.98}Sb$	27.1	2.3	2.2	2.4	32.7	33.3

Table S4. The fitting parameters for the Nb_{1-x-y-z}Ti_xZr_yHf_zFeSb (x, y, z = 0, 0.05, 0.06, 0.07) samples.

Nominal	<i>ε</i> (G=0)	A	В	С
composition		$(10^{-43} \mathrm{s}^3)$	(10 ⁻¹⁸ s/K)	(10 ⁻¹⁶ s)
x = y = z = 0	1.45	0	1.45	2.50
x = 0.05, y = z = 0	30.7	1.01	1.80	2.70
x = y = 0.05, z = 0	33.9	2.36	1.65	3.00
x = y = z = 0.05	36.3	7.62	1.40	3.20
x = y = z = 0.06	28.5	8.37	1.95	3.60
x = y = z = 0.07	33.3	11.9	1.10	4.00

Table S5. The atom radius and mass of Nb, Ti, Zr, Hf element.

	Nb	Ti	Zr	Hf
Radius (pm)	146	147	160	159
Mass (g cm ⁻¹)	92.91	47.87	91.22	178.49

Table S6. The Young's modulus (E) bulk modulus (K), and compression modulus (E_s) of the Nb_{1-x-y-}

 $_{z}$ Ti_xZr_yHf_zFeSb (x, y, z = 0, 0.05, 0.06, 0.07) samples.

<i>x</i> , <i>y</i> , <i>z</i>	E (GPa)	K (GPa)	$E_{\rm s}({\rm GPa})$
x = y = z = 0	261.0	133.7	25.5
x = 0.05, y = z = 0	293.0	157.7	38.4
x = y = 0.05, z = 0	295.4	164.2	39.2
x = y = z = 0.05	267.3	151.9	35.9
x = y = z = 0.06	283.1	148.7	31.8
x = y = z = 0.07	258.6	142.9	37.5

Modeling of lattice thermal conductivity

Based on the Debye-Callaway theory, the κ_{lat} can be expressed as:

$$\kappa_{\rm L} = \int_{0}^{\frac{\theta_{\rm D}}{T}} \kappa_{\rm S}(\mathbf{x}) d\mathbf{x} = \frac{k_{\rm B}}{2\pi^2 v_{\rm a}} \left(\frac{k_{\rm B}}{\hbar} \right)^3 T^3 \int_{0}^{\theta_{\rm D}/T} \tau(\mathbf{x}) \frac{x^4 e^x}{(e^x - 1)^2} dx$$
(1)

where $x = \hbar^{W}/(k_{B}T)$ is the reduced phonon frequency, k_{B} , \hbar , θ_{D} are the Boltzmann

constant, the reduced Planck constant, the Debye temperature, respectively. τ is the sum of the relaxation times from different scattering mechanisms. Here, we mainly focus on the phonon-phonon Umklapp process (U), the point defect scattering (PD), the grain boundary scattering (GB) and the electro-acoustic coupling (EP).

In this work, τ is expressed as:

$$\tau^{-1} = \tau_{PD}^{-1} + \tau_{U}^{-1} + \tau_{GB}^{-1} + \tau_{EP}^{-1} = A\omega^{4} + B\omega^{2}T \exp\left(-\frac{\theta_{D}}{3T}\right) + \frac{v}{d} + C\omega^{2}$$
(2)

Where *d* is the grain size and *v*/*d* represents boundary scattering. *A* is the pre-factor of point defect (*PD*) scattering relaxation time due to Ti doping. *B* is the prefactor of phonon-phonon Umklapp (*U*) scattering relaxation time, and *C* is the prefactor of electron phonon (*EP*) scattering relaxation time. For the polycrystalline pure FeNbSb, the dominated phonon scattering mechanism should be the phonon-phonon *U* scattering and boundary scattering. Therefore, through fitting the κ_1 of polycrystalline FeNbSb, we can obtain the prefactor *B* of *U* scattering relaxation time. Scattering by point defects arises from both mass and strain differences within the lattice.

In the simple case of alloying:

$$\tau_{PD}^{-1} = \frac{V\omega^4}{4\pi v_a^{-3}} (\Gamma_m + \Gamma_s)$$
(3)

Where V is the volume per atom, v_a is the average velocity. Γ_m and Γ_s are the disorder scattering parameters of mass and strain field fluctuation, respectively. We can obtain the prefactor A of point defect (PD) scattering relaxation time, the mass fluctuation (Γ_m) and strain field term (Γ_s) parameter are then given by

where \overline{M}_i is the average atomic mass of the *i* of sublattice, the $\overline{\overline{M}}$ is the average atomic mass of the compound, f_i is the fractional occupant, r_i is the radius of atom, ε is the phenomenological parameter which is a function of the Grüneisen parameter. The mass fluctuation term and the strain field term would be jointly determined by four or five parameters of \overline{M}_i , $\overline{\overline{M}}$, f_i , r_i , ε , respectively.

For Nb_{1-x-y-z}Ti_xZr_yHf_zFeSb (x, y, z = 0, 0.05, 0.06, 0.07) samples, the existing phonon scattering sources should be the *U* process, boundary, point defects and electron-phonon interaction. The boundary scattering and point defects scattering relaxation times can be calculated independently. Therefore, through fitting the κ_1 of corresponding sample, the prefactor *C* of the *EP* scattering relaxation time can be obtained.

Calculation of bulk modulus

The bulk modulus (*K*) has been calculated using the following equations:

$$K = \frac{E}{3(1 - 2v_{\rm p})}$$
(6)

$$E = \frac{\rho v_{a}^{2} (3v_{1}^{2} - 4v_{t}^{2})}{(v_{1}^{2} - v_{t}^{2})}$$
(7)

$$v_{\rm p} = \frac{1 - 2(v_{\rm t}/v_{\rm l})^2}{2 - 2(v_{\rm t}/v_{\rm l})^2} \tag{8}$$

Where E, v_p , v_a , v_l and v_t are the Young's modulus, Poisson's ratio, average sound

velocity, longitudinal sound velocity and transverse sound velocity, respectively.